## NSN 5961-00-420-7399

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-420-7399 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-99 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open all transistor and 7.0 emitter to base voltage, static, collector open all transistor and 60.0 collector to emitter voltage/static/base open all transistor **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Internal junction configuration transistor npn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 6 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/270 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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No